



A rapid hydrothermal synthesis of rutile SnO₂ nanowires

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ABSTRACT

Tin oxide (SnO₂) nanowires with rutile structure have been synthesized by a facile hydrothermal method at 98 °C. The morphologies and structural properties of the as-grown nanowires/nanoneedles were characterized by scanning electron microscopy (SEM), transmission electron microscopy (TEM), selected area electron diffraction, X-ray diffraction and Raman spectroscopy. The SEM images reveal tetragonal nanowires of about 10–100 μm in length and 50–100 nm in radius. The Raman scattering peaks indicate a typical rutile phase of the SnO₂. The effects of molar ratio of SnCl₄ to NH₄OH on the growth mechanism are discussed.

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1. Introduction

A new generation of one-dimensional (1D) nanoarchitectures, such as nanowires, nanorods and nanoneedles has been produced and attracted considerable attention in the materials research community [1]. The interest is motivated by the physical and chemical properties, which are highly dependent on the aspect ratio and shape [1,2]. Extensive efforts have been made on developing new methods to synthesize, manipulate and tailoring functionalities of a variety of 1D nanostructured materials (SnO₂, ZnO, CdS, In₂O₃, etc.) [1–3]. Among them, rutile SnO₂, an n-type semiconductor with a wide band gap (E_g = 3.62 eV at 300 K), and excellent optical and electrical properties, is a strategic material for a range of technological applications [4]. Its practical uses include ultrasensitive gas sensors [5], optoelectronic devices [6], electrodes for solar cells [4] and anode material for lithium batteries [7].

SnO₂ nanoarchitectures have been synthesized by the self-catalytic vapor–liquid–solid (VLS) method [6], calcination process [7], chemical vapor deposition [8], thermal evaporation [1], hydrothermal [9], laser ablation technique [10], solvothermal [11] and carbothermal reduction [12]. These techniques all require a growth temperature of 900 °C or higher, which makes them difficult for certain device applications and which are often difficult

to control reproducibly [13]. Guo et al. [14] has reported a low-temperature hydrothermal synthesis of SnO₂ nanorods at 160 °C, but the process requires at least 12 h. Vayssieres and Graetzel [15] reported SnO₂ nanorods arrays grown on F-SnO₂ glass substrates by aqueous thermohydrolysis at 95 °C.

This paper presents an inexpensive and rapid fabrication technique for one-dimensional (1D) tin oxide (SnO₂) nanowires with rutile structure synthesized by a facile hydrothermal method at 95–98 °C for 15 min. It permits rapid and controlled growth of tin oxide nanowires without the use of templates or seeds. The obtained tin oxide nanowires are distributed on the surface of Si/SiO₂ substrates and individual nanowires can be easily transferred to other substrates which are decisive factor for single nanowire ultrasensitive sensors fabrication.

Our technique is faster and cost-effective, which is important for large scale applications in nanoelectronics/nanotechnologies and can find a wide range of applications.

2. Experimental

Rutile-structured SnO₂ nanowires/nanoneedles were synthesized at a low temperature by a hydrothermal method without any other seeds, templates or surfactant. A solution containing tin chloride [SnCl₄·5H₂O, 0.01–0.03 M] (purity 99.5%) and ammonia [NH₄(OH), 29.5%] (Fisher Scientific) was employed for growth of tin oxide nanowires and nanoneedles. Both reagents were used in the received form without further purification. A hydrothermal reactor [3] with a cap was filled with aqueous solution. In a typical procedure, Si wafers and glass substrates were cleaned according to

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